

# ANTREX Electronics

## Electronic Components Sourcing Information

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### Product Reference Information

|                      |                           |
|----------------------|---------------------------|
| <b>Part Number:</b>  | PUMD16,115                |
| <b>Manufacturer:</b> | Nexperia USA Inc.         |
| <b>Package:</b>      | 6-TSSOP, SC-88, SOT-363   |
| <b>Availability:</b> | Please confirm with sales |

#### Product Page:

<https://antrexco.com/product/details/nexperia-usa-inc/pumd16-115.html>

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#### Note:

This PDF includes an ANTREX product reference cover page.

The original manufacturer datasheet follows from the next page.



# PUMD16

50 V, 100 mA NPN/PNP resistor-equipped double transistor;  
R1 = 22 k $\Omega$ , R2 = 47 k $\Omega$

27 July 2026

Product data sheet

## 1. General description

NPN/PNP double Resistor-Equipped Transistor (RET) in a very small SOT363-3 (SC-88) Surface-Mounted Device (SMD) plastic package.

NPN/NPN complement: PUMH16

PNP/PNP complement: PUMB16

## 2. Features and benefits

- 100 mA output current capability
- Built-in bias resistors
- Simplified circuit design
- Reduces component count
- Reduces pick and place costs

## 3. Applications

- Low current peripheral driver
- Controlling IC inputs
- Replacement of general purpose transistors in digital applications

## 4. Quick reference data

Table 1. Quick reference data

| Symbol                | Parameter                 | Conditions |     | Min  | Typ | Max  | Unit       |
|-----------------------|---------------------------|------------|-----|------|-----|------|------------|
| <b>Per transistor</b> |                           |            |     |      |     |      |            |
| V <sub>CEO</sub>      | collector-emitter voltage | open base  | [1] | -    | -   | 50   | V          |
| I <sub>O</sub>        | output current            |            | [1] | -    | -   | 100  | mA         |
| R1                    | bias resistor 1 (input)   |            | [2] | 15.4 | 22  | 28.6 | k $\Omega$ |
| R2/R1                 | bias resistor ratio       |            | [2] | 1.7  | 2.1 | 2.6  |            |

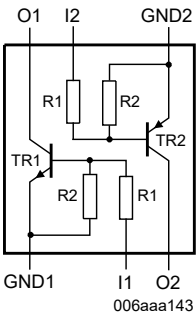
[1] For the PNP transistor with negative polarity.

[2] See section "Test information" for resistor calculation and test conditions.

50 V, 100 mA NPN/PNP resistor-equipped double transistor; R1 = 22 kΩ, R2 = 47 kΩ

5. Pinning information

Table 2. Pinning information

| Pin | Symbol | Description            | Simplified outline                                                                                                                                | Graphic symbol                                                                                       |
|-----|--------|------------------------|---------------------------------------------------------------------------------------------------------------------------------------------------|------------------------------------------------------------------------------------------------------|
| 1   | GND1   | GND (emitter) TR1      |  <p>Transparent<br/>top view</p> <p><b>TSSOP6 (SOT363-3)</b></p> |  <p>006aaa143</p> |
| 2   | I1     | input (base) TR1       |                                                                                                                                                   |                                                                                                      |
| 3   | O2     | output (collector) TR2 |                                                                                                                                                   |                                                                                                      |
| 4   | GND2   | GND (emitter) TR2      |                                                                                                                                                   |                                                                                                      |
| 5   | I2     | input (base) TR2       |                                                                                                                                                   |                                                                                                      |
| 6   | O1     | output (collector) TR1 |                                                                                                                                                   |                                                                                                      |

6. Ordering information

Table 3. Ordering information

| Type number            | Package |                                          |                          |
|------------------------|---------|------------------------------------------|--------------------------|
|                        | Name    | Description                              | Version                  |
| <a href="#">PUMD16</a> | TSSOP6  | Plastic surface-mounted package; 6 leads | <a href="#">SOT363-3</a> |

7. Marking

Table 4. Marking codes

| Type number | Marking code[1] |
|-------------|-----------------|
| PUMD16      | D1 %            |

[1] % = placeholder for manufacturing site code

8. Limiting values

Table 5. Limiting values  
In accordance with the Absolute Maximum Rating System (IEC 60134).

| Symbol           | Parameter                 | Conditions               |     | Min | Max | Unit |
|------------------|---------------------------|--------------------------|-----|-----|-----|------|
| Per transistor   |                           |                          |     |     |     |      |
| V <sub>CBO</sub> | collector-base voltage    | open emitter             | [1] | -   | 50  | V    |
| V <sub>CEO</sub> | collector-emitter voltage | open base                | [1] | -   | 50  | V    |
| V <sub>EBO</sub> | emitter-base voltage      | open collector           | [1] | -   | 5   | V    |
| V <sub>I</sub>   | input voltage             | TR1 (NPN)                |     | -7  | 40  | V    |
|                  |                           | TR2 (PNP)                |     | -40 | 7   | V    |
| I <sub>O</sub>   | output current            |                          | [1] | -   | 100 | mA   |
| P <sub>tot</sub> | total power dissipation   | T <sub>amb</sub> ≤ 25 °C | [2] | -   | 200 | mW   |
| Per device       |                           |                          |     |     |     |      |
| P <sub>tot</sub> | total power dissipation   | T <sub>amb</sub> ≤ 25 °C | [2] | -   | 300 | mW   |
| T <sub>j</sub>   | junction temperature      |                          |     | -   | 150 | °C   |
| T <sub>amb</sub> | ambient temperature       |                          |     | -65 | 150 | °C   |
| T <sub>stg</sub> | storage temperature       |                          |     | -65 | 150 | °C   |

[1] For the PNP transistor with negative polarity.  
[2] Device mounted on an FR4 Printed-Circuit Board (PCB), single-sided copper, tin-plated and standard footprint.

9. Thermal characteristics

Table 6. Thermal characteristics

| Symbol               | Parameter                                   | Conditions  |     | Min | Typ | Max | Unit |
|----------------------|---------------------------------------------|-------------|-----|-----|-----|-----|------|
| Per transistor       |                                             |             |     |     |     |     |      |
| R <sub>th(j-a)</sub> | thermal resistance from junction to ambient | in free air | [1] | -   | -   | 625 | K/W  |
| Per device           |                                             |             |     |     |     |     |      |
| R <sub>th(j-a)</sub> | thermal resistance from junction to ambient | in free air | [1] | -   | -   | 417 | K/W  |

[1] Device mounted on an FR4 PCB, single-sided copper, tin-plated and standard footprint.

## 10. Characteristics

Table 7. Characteristics

| Symbol                | Parameter                            | Conditions                                                                                                                    |     | Min  | Typ | Max  | Unit          |
|-----------------------|--------------------------------------|-------------------------------------------------------------------------------------------------------------------------------|-----|------|-----|------|---------------|
| <b>Per transistor</b> |                                      |                                                                                                                               |     |      |     |      |               |
| $V_{(BR)CBO}$         | collector-base breakdown voltage     | $I_C = 100\text{ }\mu\text{A}$ ; $I_E = 0\text{ A}$ ; $T_{amb} = 25\text{ }^\circ\text{C}$                                    | [1] | 50   | -   | -    | V             |
| $V_{(BR)CEO}$         | collector-emitter breakdown voltage  | $I_C = 2\text{ mA}$ ; $I_B = 0\text{ A}$ ; $T_{amb} = 25\text{ }^\circ\text{C}$                                               | [1] | 50   | -   | -    | V             |
| $I_{CBO}$             | collector-base cut-off current       | $V_{CB} = 50\text{ V}$ ; $I_E = 0\text{ A}$ ; $T_{amb} = 25\text{ }^\circ\text{C}$                                            | [1] | -    | -   | 100  | nA            |
| $I_{CEO}$             | collector-emitter cut-off current    | $V_{CE} = 30\text{ V}$ ; $I_B = 0\text{ A}$ ; $T_{amb} = 25\text{ }^\circ\text{C}$                                            | [1] | -    | -   | 100  | nA            |
|                       |                                      | $V_{CE} = 30\text{ V}$ ; $I_B = 0\text{ A}$ ; $T_j = 150\text{ }^\circ\text{C}$                                               | [1] | -    | -   | 5    | $\mu\text{A}$ |
| $I_{EBO}$             | emitter-base cut-off current         | $V_{EB} = 5\text{ V}$ ; $I_C = 0\text{ A}$ ; $T_{amb} = 25\text{ }^\circ\text{C}$                                             | [1] | -    | -   | 120  | $\mu\text{A}$ |
| $h_{FE}$              | DC current gain                      | $V_{CE} = 5\text{ V}$ ; $I_C = 5\text{ mA}$ ; $T_{amb} = 25\text{ }^\circ\text{C}$                                            | [1] | 80   | -   | -    |               |
| $V_{CEsat}$           | collector-emitter saturation voltage | $I_C = 10\text{ mA}$ ; $I_B = 0.5\text{ mA}$ ; $T_{amb} = 25\text{ }^\circ\text{C}$                                           | [1] | -    | -   | 150  | mV            |
| $V_{I(off)}$          | off-state input voltage              | $V_{CE} = 5\text{ V}$ ; $I_C = 100\text{ }\mu\text{A}$ ; $T_{amb} = 25\text{ }^\circ\text{C}$                                 | [1] | -    | 0.8 | 0.5  | V             |
| $V_{I(on)}$           | on-state input voltage               | $V_{CE} = 0.3\text{ V}$ ; $I_C = 2\text{ mA}$ ; $T_{amb} = 25\text{ }^\circ\text{C}$                                          | [1] | 2    | 1.1 | -    | V             |
| R1                    | bias resistor 1 (input)              |                                                                                                                               | [2] | 15.4 | 22  | 28.6 | k $\Omega$    |
| R2/R1                 | bias resistor ratio                  |                                                                                                                               | [2] | 1.7  | 2.1 | 2.6  |               |
| <b>TR1 (NPN)</b>      |                                      |                                                                                                                               |     |      |     |      |               |
| $C_c$                 | collector capacitance                | $V_{CB} = 10\text{ V}$ ; $I_E = 0\text{ A}$ ; $i_e = 0\text{ A}$ ; $f = 1\text{ MHz}$ ; $T_{amb} = 25\text{ }^\circ\text{C}$  |     | -    | -   | 2.5  | pF            |
| <b>TR2 (PNP)</b>      |                                      |                                                                                                                               |     |      |     |      |               |
| $C_c$                 | collector capacitance                | $V_{CB} = -10\text{ V}$ ; $I_E = 0\text{ A}$ ; $i_e = 0\text{ A}$ ; $f = 1\text{ MHz}$ ; $T_{amb} = 25\text{ }^\circ\text{C}$ |     | -    | -   | 3    | pF            |

[1] For the PNP transistor with negative polarity.

[2] See section "Test information" for resistor calculation and test conditions.

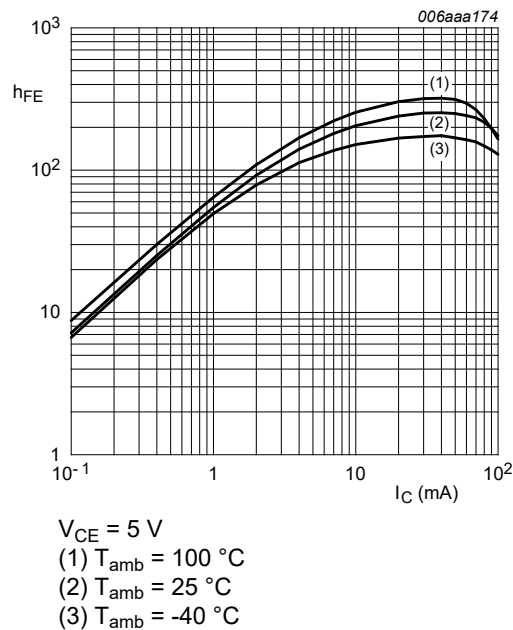


Fig. 1. TR1 (NPN): DC current gain as a function of collector current; typical values

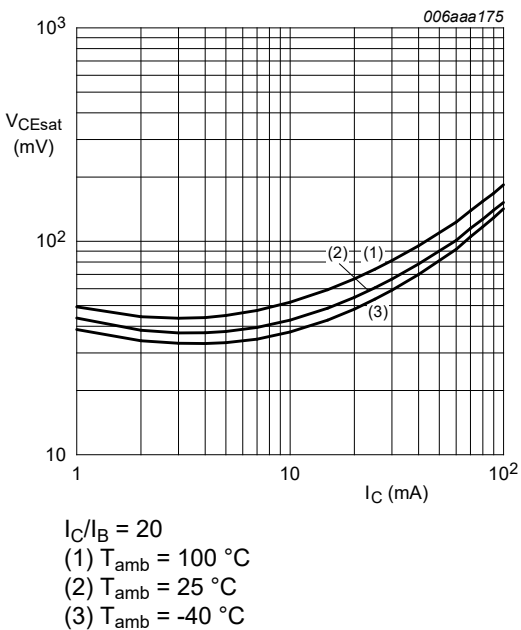


Fig. 2. TR1 (NPN): Collector-emitter saturation voltage as a function of collector current; typical values

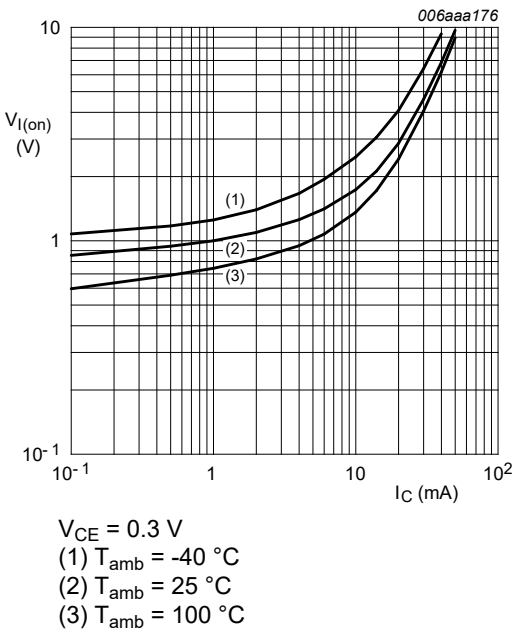


Fig. 3. TR1 (NPN): On-state input voltage as a function of collector current; typical values

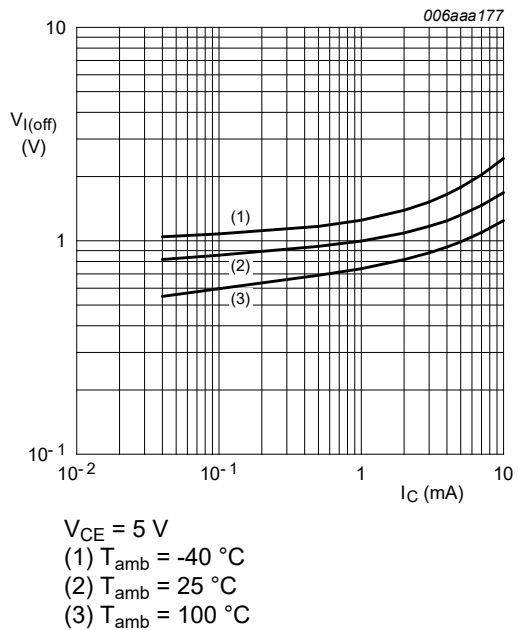


Fig. 4. TR1 (NPN): Off-state input voltage as a function of collector current; typical values

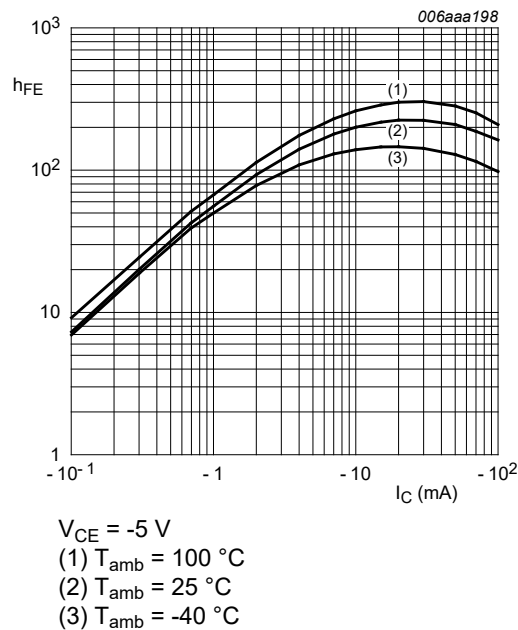


Fig. 5. TR2 (PNP): DC current gain as a function of collector current; typical values

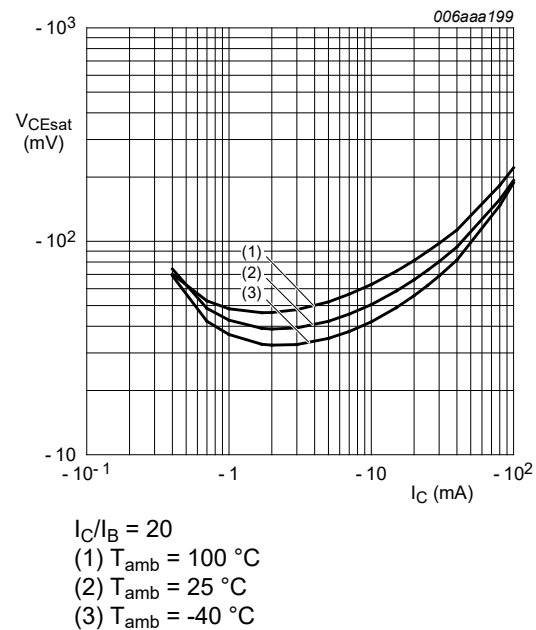


Fig. 6. TR2 (PNP): Collector-emitter saturation voltage as a function of collector current; typical values

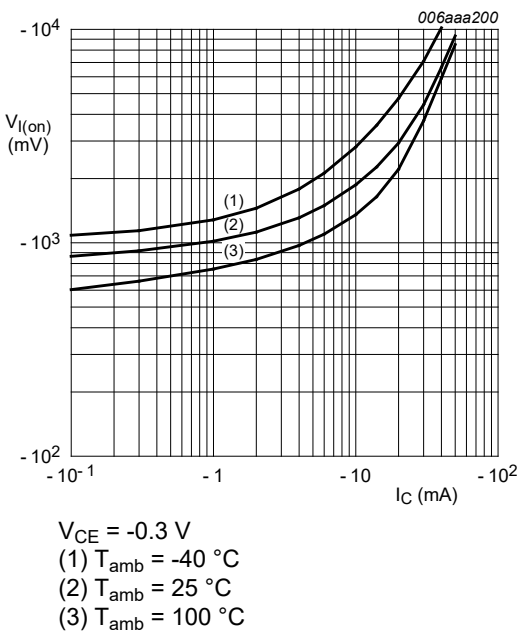


Fig. 7. TR2 (PNP): On-state input voltage as a function of collector current; typical values

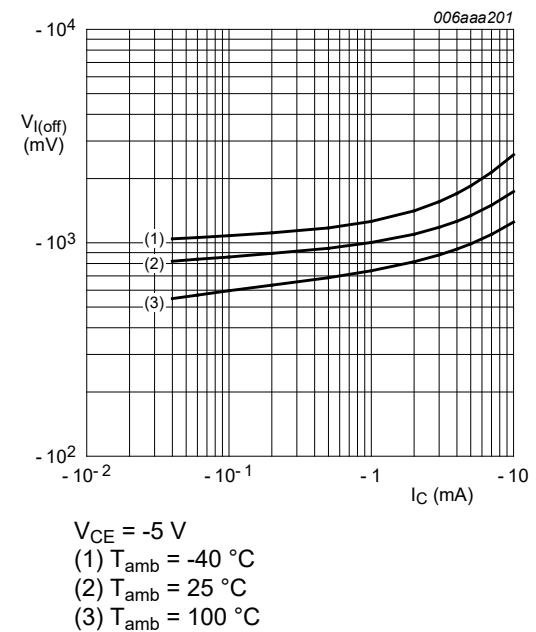


Fig. 8. TR2 (PNP): Off-state input voltage as a function of collector current; typical values

11. Test information

Resistor calculation

- Calculation of bias resistor 1 (R1)

$$R_1 = \frac{V(I_2) - V(I_1)}{I_2 - I_1}$$

- Calculation of bias resistor ratio (R2/R1)

$$\frac{R_2}{R_1} = \frac{V(I_4) - V(I_3)}{R_1 \cdot (I_4 - I_3)} - 1$$

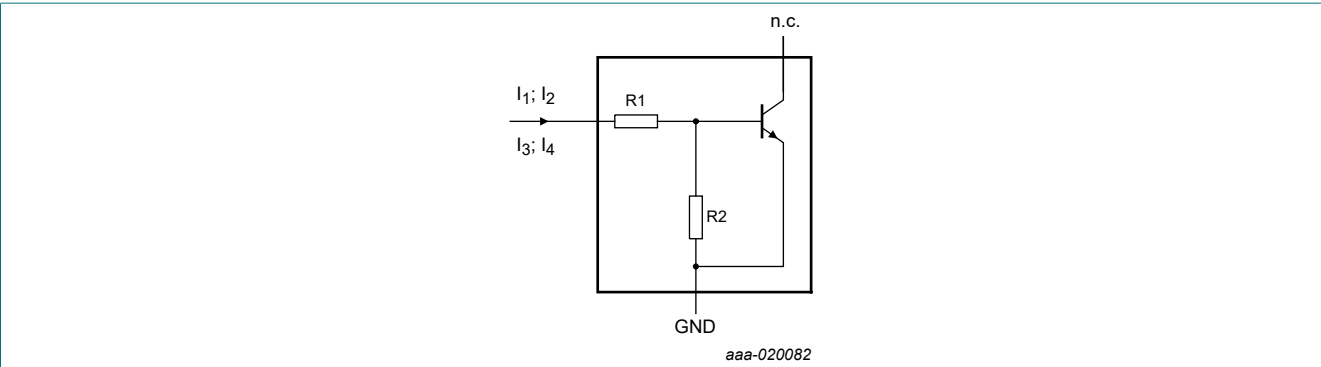


Fig. 9. NPN transistor: Resistor test circuit

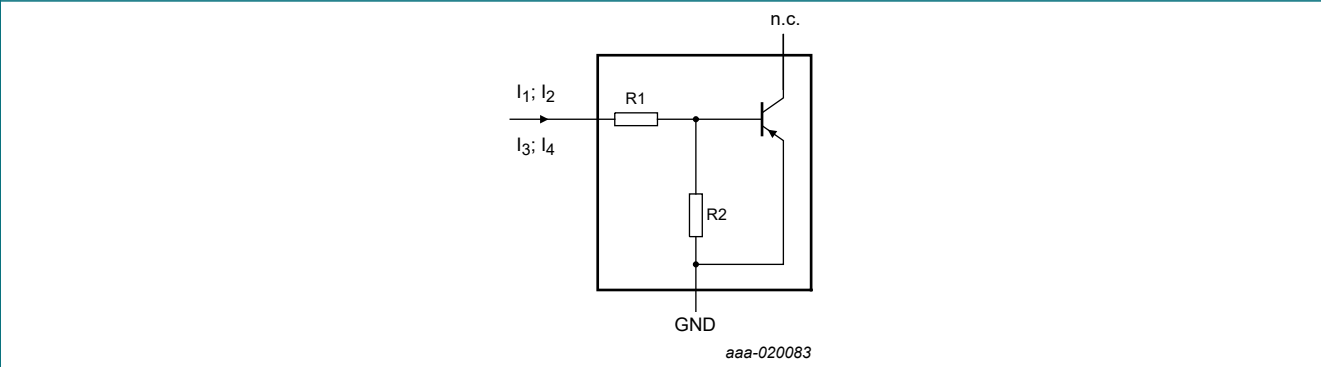


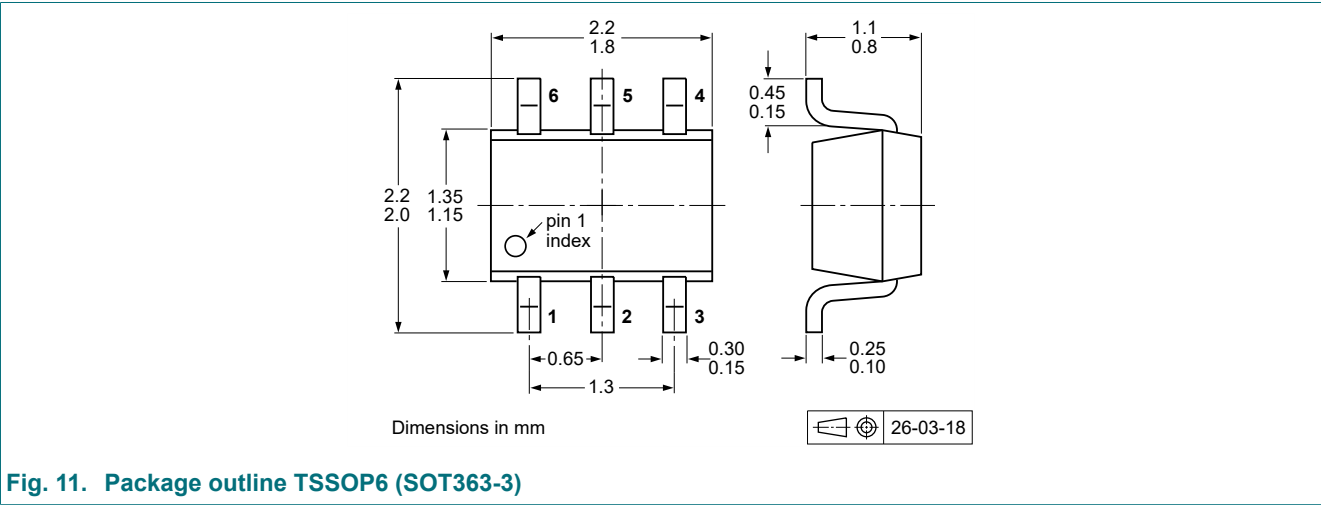
Fig. 10. PNP transistor: Resistor test circuit

Resistor test conditions

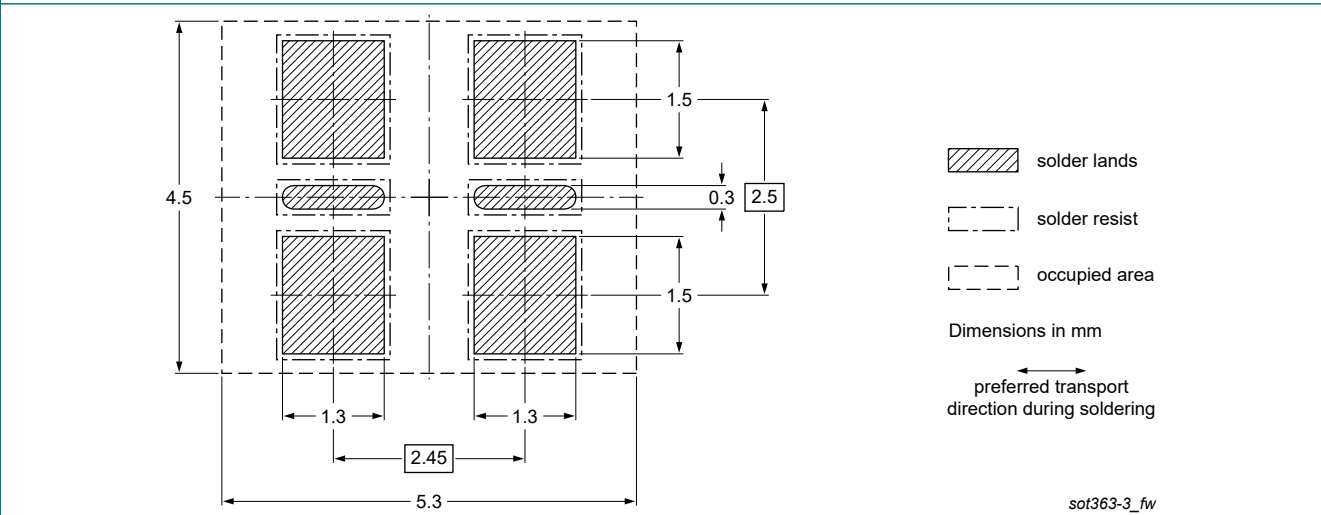
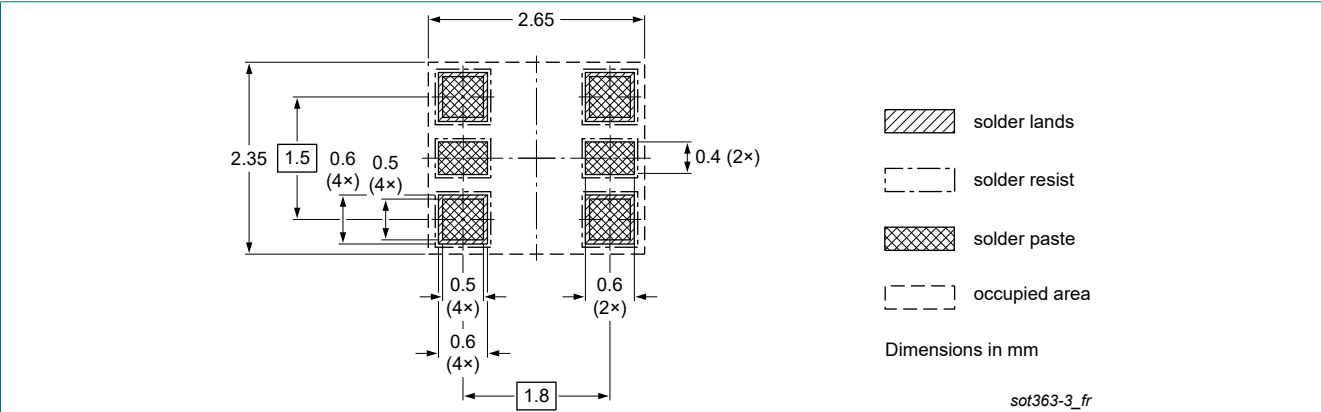
Table 8. Resistor test conditions

| PUMD16    | R1 (kΩ) | R2 (kΩ) | Test conditions |                |                |                |
|-----------|---------|---------|-----------------|----------------|----------------|----------------|
|           |         |         | I <sub>1</sub>  | I <sub>2</sub> | I <sub>3</sub> | I <sub>4</sub> |
| TR1 (NPN) | 22      | 47      | 55 μA           | 105 μA         | -55 μA         | -105 μA        |
| TR2 (PNP) | 22      | 47      | -55 μA          | -105 μA        | 55 μA          | 105 μA         |

12. Package outline



13. Soldering



14. Revision history

Table 9. Revision history

| Data sheet ID     | Release date                              | Data sheet status     | Change notice | Supersedes        |
|-------------------|-------------------------------------------|-----------------------|---------------|-------------------|
| PUMD16 v.6        | 20260727                                  | Product data sheet    | -             | PUMD16 v.5        |
| Modifications:    | • Package changed from SOT363 to SOT363-3 |                       |               |                   |
| PUMD16 v.5        | 20250507                                  | Product data sheet    | -             | PUMD16 v.4        |
| PUMD16 v.4        | 20230331                                  | Product data sheet    | -             | PEMD16_PUMD16 v.3 |
| PEMD16_PUMD16 v.3 | 20110628                                  | Product data sheet    | -             | PEMD16_PUMD16 v.2 |
| PEMD16_PUMD16 v.2 | 20050607                                  | Product data sheet    | -             | PUMD16 v.1        |
| PUMD16 v.1        | 20031022                                  | Product specification | -             | -                 |

# 15. Legal information

## Data sheet status

| Document status [1][2]         | Product status [3] | Definition                                                                            |
|--------------------------------|--------------------|---------------------------------------------------------------------------------------|
| Objective [short] data sheet   | Development        | This document contains data from the objective specification for product development. |
| Preliminary [short] data sheet | Qualification      | This document contains data from the preliminary specification.                       |
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Contents

1. General description..... 1

2. Features and benefits..... 1

3. Applications..... 1

4. Quick reference data..... 1

5. Pinning information.....2

6. Ordering information.....2

7. Marking.....2

8. Limiting values..... 3

9. Thermal characteristics..... 3

10. Characteristics..... 4

11. Test information..... 7

12. Package outline..... 8

13. Soldering..... 8

14. Revision history.....9

15. Legal information.....10

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